

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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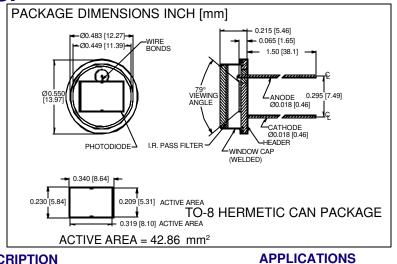




## **PHOTONIC** DETECTORS INC.

### Silicon Photodiode, Near I.R. Photovoltaic Type PDI-V109-F





#### **FEATURES**

- Low noise
- Match to I.R. emitters
- Hermetic package

#### **DESCRIPTION**

The PDI-V109-F is a silicon, PIN planar • I.R. pass visible rejection diffused photodiode with NIR pass, visible light rejection optical filter. Ideal for low noise photovoltaic NIR applications. Packaged in a hermetic TO-8 metal can with a

### • I.R. laser detector Photo-interrupters

• I.R. detector

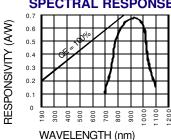
Industrial controls

flat window cap. **ABSOLUTE MAXIMUM RATING** (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V <sub>BR</sub>	Reverse Voltage		100	V
T <sub>STG</sub>	Storage Temperature	-55	+100	°C
То	Operating Temperature Range	-40	+80	°C
Ts	Soldering Temperature*		+240	°C
I	Light Current		1.0	mA

<sup>\*1/16</sup> inch from case for 3 secs max

#### **SPECTRAL RESPONSE**



#### **ELECTRO-OPTICAL CHARACTERISTICS** (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
lsc	Short Circuit Current	H = 100 fc, 2850 K	365	405		mA
ΙD	Dark Current	$H = 0, V_{R} = 10 \text{ mV}$		66	200	рА
Rsh	Shunt Resistance	$H = 0, V_{R} = 10 \text{ mV}$	50	150		MΩ
TC Rsh	RSH Temp. Coefficient	$H = 0, V_{R} = 10 \text{ mV}$		-8		%/℃
C	Junction Capacitance	$H = 0, V_{R} = 0 V^{**}$		4,500		pF
λrange	Spectral Application Range	Spot Scan	700		1100	nm
λр	Spectral Response - Peak	Spot Scan		950		nm
V <sub>BR</sub>	Breakdown Voltage	I = 10 <b>m</b> A	20	30		V
N EP	Noise Equivalent Power	VR = 10 mV @ Peak		1.0x10 <sup>-14</sup>		W/ <del>V Hz</del>
tr	Response Time	$RL = 1 K\Omega V_R = 0 V$		1000		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. \*\* f = 1 MHz